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L	Hits	Search Text	DB	Time stamp
Number				
1	33928	semiconductor and (bipolar adj	USPAT;	2003/09/10
		transistor)	US-PGPUB;	08:21
			EPO; JPO;	
			DERWENT;	l i
			IBM_TDB	
2	9175	(semiconductor and (bipolar adj	USPAT;	2003/09/10
		transistor)) and ((polycrystal\$4 adj	US-PGPUB;	08:21
		(silicon or si)) or polysilicon)	EPO; JPO;	
			DERWENT;	
	1		IBM TDB	
3	489	((semiconductor and (bipolar adj	USPAT;	2003/09/10
_		transistor)) and ((polycrystal\$4 adj	US-PGPUB;	08:22
		(silicon or si)) or polysilicon)) and	EPO; JPO;	
		(rapid adj thermal adj anneal\$3)	DERWENT;	
			IBM TDB	
4	5	(((semiconductor and (bipolar adj	USPAT;	2003/09/10
		transistor)) and ((polycrystal\$4 adj	US-PGPUB;	08:22
		(silicon or si)) or polysilicon)) and	EPO; JPO;	
		(rapid adj thermal adj anneal\$3)) and	DERWENT;	
		(residual adj oxide)	IBM TDB	